







## Molecular beam epitaxy of superconducting $\text{FeSe}_x\text{Te}_{1-x}$ thin films interfaced with magnetic topological insulators

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Engineering heterostructures with various types of quantum materials can provide an intriguing playground for studying exotic physics induced by the proximity effect. Here, we report on the successful synthesis of iron-based superconductor  $\text{FeSe}_x\text{Te}_{1-x}$  (FST) thin films across the entire composition range of  $0 \leq x \leq 1$  and its heterostructure with a magnetic topological insulator (TI) by using molecular beam epitaxy. Superconductivity is observed in the FST films with an optimal superconducting transition temperature  $T_c \sim 12$  K at around  $x = 0.1$ . We found that superconductivity survives in the very Te-rich films ( $x \leq 0.05$ ), showing stark contrast with bulk crystals with suppression of superconductivity due to an appearance of bicollinear antiferromagnetism accompanied by a monoclinic structural transition. By examining thickness  $t$  dependence of magnetic susceptibility and electrical transport properties, we observed a trend where anomalies associated with the first-order structural transition broaden in films with below  $t \sim 100$  nm. We infer this observation suggests a suppression of the structural instability near substrates. Furthermore, we fabricated an all chalcogenide-based heterointerface between FST and a magnetic TI  $(\text{Cr, Bi, Sb})_2\text{Te}_3$ , observing both superconductivity and a large anomalous Hall conductivity. The anomalous Hall conductivity increases with decreasing temperature, approaching the quantized value of  $e^2/h$  down to the measurable minimum temperature at  $T_c$ . The result suggests coexistence of magnetic and superconducting gaps at low temperatures opening at the top and bottom surfaces, respectively. Our magnetic TI/superconductor heterostructure could be an ideal platform to explore chiral Majorana edge mode.

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**Introduction.** An interface between different types of quantum materials can host exotic physics originating from nontrivial topology, the proximity effect, and broken inversion symmetry. Engineering heterointerfaces may facilitate the establishment of a topological superconductor as a platform for detecting and manipulating Majorana quasiparticles. It has been proposed that Majorana zero mode can be realized at the core of a superconducting vortex in bulk superconductors with a superconducting gap possessing nontrivial topology [1,2]. Another proposed approach is to introduce the superconducting proximity effect on the surface states of a topological insulator (TI) [3]. Advances in thin film growth techniques have enabled us to fabricate them with great controllability in their electronic structures. For example, it has been established that one can materialize a quantum anomalous Hall (QAH) insulator by substituting magnetic ions in prototypical chalcogenide TI thin films of  $(\text{Bi, Sb})_2\text{Te}_3$  and electrostatically tuning their Fermi level within the mass gap [4,5]. One successful example is  $(\text{Cr, Bi, Sb})_2\text{Te}_3$  (CBST), where inclusion of Cr introduces ferromagnetic (FM) ordering below

the Curie temperature  $T_{\text{Curie}}$  and opens a magnetic gap in the Dirac cone. When such a QAH insulator is proximitized to a superconductor, a nontrivial superconducting phase with broken time-reversal symmetry is expected, leading to the emergence of a chiral Majorana edge mode [6]. To achieve proximity-induced topological superconductivity, a high-quality interface would be required so that wave functions of two different materials can be hybridized with each other.

One of the promising candidates for a topological superconductor is iron-based superconductor  $\text{FeSe}_x\text{Te}_{1-x}$  (FST). FST has the simplest crystal structure among the iron-based superconductor materials family, which only consists of quasi-two-dimensional stacks of iron-chalcogen sheets. While  $\text{FeSe}$  ( $x = 1$ ) is a trivial superconductor, isovalent Te substitution into Se can enhance spin-orbit coupling, and it is claimed that a topologically nontrivial phase is realized at  $x = 0.5$ , by first-principles calculation and angle-resolved photoemission spectroscopy (ARPES) [7]. As the topological surface state is expected to be directly proximitized to its bulk superconductivity below the superconducting transition temperature  $T_c$ , the surface of FST can be regarded as a two-dimensional  $p$ -wave superconductor. Indeed, the topological surface state and isotropic gap at the Dirac cone are observed by ARPES [8], providing evidence for

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topological superconductivity. Furthermore, scanning tunneling microscopy (STM) reveals a zero-bias peak in tunneling conductance [9–11], suggesting the presence of a Majorana zero mode in vortex cores. Another remarkable feature of FST is its excellent affinity to chalcogenide TI thin films. It is reported that TI thin film  $\text{Bi}_2\text{Te}_3$  (BT), thanks to its van der Waals stacking nature, can be epitaxially grown on top of the parent compound  $\text{FeTe}$  ( $x = 0$ ) using the molecular beam epitaxy (MBE) technique [12]. Additionally, non-reciprocal transport is observed in this all chalcogenide-based heterostructure, suggesting the crucial roles of the proximity effect and broken inversion symmetry [13].

However, the tunneling conductance peaks observed in the STM studies do not always appear at zero energy, suggesting that a trivial origin can also play a role [14]. One plausible obstacle is the inevitable inhomogeneity in the sample near the half composition  $x = 0.5$ , where FST phase-separates into Se- and Te-rich clusters. It is proposed that the inhomogeneity causes topological phase separation, and signatures of the nontrivial phase can be found only in the Te-rich region [10,15]. Although such inhomogeneity might be suppressed in FST near the end compound  $\text{FeTe}$ , it enters a bicollinear antiferromagnetic (AFM) state below  $x \sim 0.05$  accompanied by a monoclinic structural transition at  $\sim 70$  K [16], which readily destroys superconductivity [17,18]. Therefore, a Te-rich superconducting FST with negligible inhomogeneity and strong spin-orbit coupling, which can further stabilize the topological superconducting phase, is in high demand but still lacking.

In this paper, we demonstrate successful growth of FST thin films on  $\text{CdTe}(100)$  substrate covering the entire composition of  $0 \leq x \leq 1$  by using the MBE technique. We found that all FST films with a thickness  $t = 40$  nm exhibit superconductivity, with an optimal  $T_c \sim 12$  K observed at around  $x = 0.1$ . Surprisingly, superconductivity survives even in films with a very rich Te content, showing a stark contrast to the behavior observed in bulk crystals. By tracking magnetic and transport properties with varying  $t$ , we found that anomalies associated with the structural transition are weak in films thinner than  $\sim 100$  nm. This observation may suggest that the substrate effect suppresses the structural transition and modifies the electronic structure near the interface. We further engineered an all-chalcogenide-based heterointerface between the magnetic TI CBST and the superconducting FST. The CBST/FST heterostructure exhibits both superconductivity and large anomalous Hall conductivity that approaches the quantized value of  $e^2/h$  at low temperatures. This exotic heterostructure, therefore, fulfills the prerequisite for the emergence of a chiral Majorana edge mode. Thus, in this paper, we take an important step toward establishing a topological superconductor as a materials platform to hunt for Majorana excitations.

*Method.* All thin films presented in this paper were grown by the MBE technique. The base pressure of the growth chamber was  $< 1 \times 10^{-6}$  Pa. High-purity sources of Fe (99.999%), Se (99.9999%), Te (99.999%), Cr (99.99%), Bi (99.9999%), and Sb (99.9999%) were evaporated by heating individual Knudsen cells and by stabilizing their temperatures to obtain stable and well-controlled equivalent beam fluxes. The amounts of the supplied fluxes were monitored by equivalent

pressure of the beam flux monitor. The flux ratio for FST is  $\text{Fe} : \text{Se} : \text{Te} = 1 : 10x_n : 10(1 - x_n)$ , where the beam-equivalent pressure of Fe is  $3.5 \times 10^{-6}$  Pa, and the nominal flux ratio  $x_n$  varies from 0 to 1 to control the Se content in the FST films. The flux ratio for CBST is  $\text{Cr} : \text{Bi} : \text{Sb} : \text{Te} = 1 : 19 : 30 : 175$ , where the beam-equivalent pressure of Cr is  $2.0 \times 10^{-7}$  Pa. Although the actual composition  $x$  in the films is found to be regulated by  $x_n$ , we calibrated  $x$  using the inductively coupled plasma mass spectrometry analysis (see details in the Supplemental Material [19]). Insulating nondoped  $\text{CdTe}(100)$  substrates with a high resistivity exceeding  $1 \times 10^7 \Omega\text{cm}$  were etched with bromine-methanol (bromine 0.01%) for 5 min before deposition [20]. Both FST and CBST were fabricated at  $240^\circ\text{C}$ . After the growth, we kept supplying Te flux during cooling samples down to  $\sim 100^\circ\text{C}$  for the FST films with  $x_n \leq 0.6$ . This Te-annealing process turns to be of great importance to improve normal-state metallicity and to stabilize superconductivity [17,19,21]. As we found the Te-annealing can also cause severe phase separation for samples with higher Se concentration ( $x_n > 0.6$ ), we annealed those Se-rich FST films in a vacuum at  $360^\circ\text{C}$  for 30 min. We found the actual Se content  $x$  is hardly affected by these annealing processes [19]. For the growth of heterostructures of the Te-rich FST and the magnetic TI CBST, we deposited CBST after the growth of FST without Te annealing. An  $\text{AlO}_x$  capping layer was deposited on CBST/FST heterostructures by atomic layer deposition immediately after taking them out of the MBE chamber. X-ray diffraction (XRD) measurements were carried out using SmartLab (RIGAKU) with  $\text{Cu } K\alpha$  x ray. Electrical transport and magnetic susceptibility measurements were performed by Physical Property Measurement System and Magnetic Property Measurement System (Quantum Design), respectively.

*Experimental Results and Discussions: Growth, characterization, and transport properties of  $\text{FeSe}_x\text{Te}_{1-x}$  thin films.* We demonstrate that FST thin films can be epitaxially grown on  $\text{CdTe}(100)$  substrate, covering the entire substitution range ( $0 \leq x \leq 1$ ). Figure 1(a) shows a cross-sectional high-angle annular dark-field scanning transmission electron microscopy (HAADF-STEM) image of an FST thin film ( $x = 0.1$ ) after the Te-annealing procedure. A sharp interface between the FST film and the  $\text{CdTe}$  substrate can be seen. The energy dispersive x-ray spectroscopy (EDX) analysis shows abrupt changes of comprising elements at the surface [Fig. 1(b)]. We note that both Se and Te are distributed homogeneously throughout the whole FST region without phase separation, which often occurs in solid-state reaction syntheses [22]. Additionally, in the capping layer, which is formed during the Te-annealing process, we found the atomic ratio of  $\text{Fe} : \text{Te} \sim 1 : 2$ , suggesting formation of an  $\text{FeTe}_2$  phase. In the Supplemental Material [19], we discuss possible formation of insulating marcasite  $\text{FeTe}_2$  on top of FST, which however should hardly affect the observed transport data of FST. XRD patterns are summarized in Fig. 1(c) for FST thin films ( $t = 40$  nm) with different nominal compositions:  $x = 0, 0.38, 0.6, 0.72, \text{ and } 1$ . Sharp peaks from FST( $00n$ ) are clearly observed for all the samples, demonstrating successful growth of homogeneous films without phase separation. These peaks are systematically shifted to higher angles as  $x$  increases. Corresponding lattice constant  $c$  is calculated from

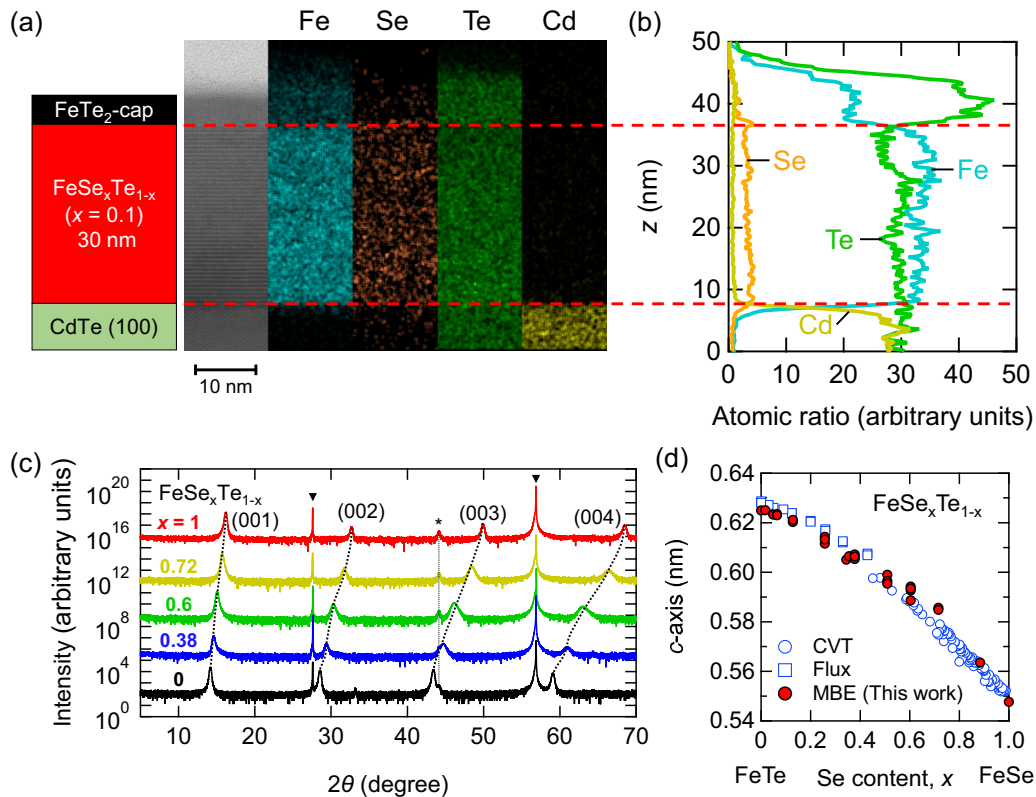


FIG. 1. Structural characterization of  $\text{FeSe}_x\text{Te}_{1-x}$  (FST) thin films. (a) Real-space characterization of FST ( $x = 0.1$ ) thin films. (left) A schematic of FST thin film. (middle) Cross-sectional high-angle annular dark-field scanning transmission electron microscopy (HAADF-STEM) image. (right four panels) Elemental mappings of comprising elements of Fe, Se, Te, and Cd studied by an energy dispersive x-ray spectroscopy (EDX) for the identical area shown in the HAADF-STEM image. The red dashed line depicts the boundary between each layer. (b) Laterally integrated atomic ratio profiles obtained by the EDX in (a). The vertical axis denotes the distance along out-of-film direction  $z$ , whose scale is the same as (a). (c) Semilog plots for x-ray diffraction (XRD) data of FST thin films ( $x = 0, 0.38, 0.6, 0.72, \text{ and } 1$ ). Each datum is vertically shifted for clarity. The dotted lines are guides for eyes, tracing the shift of main peaks from FST(00 $n$ ). The  $x$ -independent peaks (down-pointing triangle and asterisk) are from CdTe substrate. (d) Lattice constant  $c$  of FST films with  $t = 40$  nm as a function of Se content  $x$ . The open blue circle and square are reference data obtained in bulk single crystals which are grown by chemical vapor transport [24] and flux method [17], respectively.

the peak position by using Bragg's law and is plotted as a function of  $x$  in Fig. 1(d). We found the  $c$ -axis length of the films agree well with those of single crystals with a nearly linear relation, suggesting that Vegard's law holds throughout the entire substitution range. Apart from the FST(00 $n$ ) peaks, all the other features found in the XRD data can be attributed to CdTe substrate, which contributes to sharp (00 $n$ ) peaks and a tiny NaCl-type impurity phase labeled by down-pointing triangles and an asterisk, respectively.

We investigated electrical transport properties of the FST thin films. Resistivity-temperature, ( $\rho_{xx}$ - $T$ ) curves for the FST films ( $0 \leq x \leq 1$ ) with  $t = 40$  nm are presented in Figs. 2(a) and 2(b). FeTe ( $x = 0$ ) shows insulating behavior at high temperatures, peaks  $\sim 70$  K, and metallic behavior at low temperatures. As  $x$  increases, this insulator-metal crossover temperature, denoted by arrows in Fig. 2(a), tends to shift to higher temperatures. Such an insulator-metal crossover with increasing  $x$  is also reported in electrical transport [18] and ARPES studies [23] on bulk single crystals, where the Te-annealing procedure is also employed. Without the

Te-annealing procedure, the metallic behavior is absent, and the insulating behavior persists down to  $T_c$  [19]. These results suggest that the present FST thin films in Figs. 2(a) and 2(b) were sufficiently Te annealed. Although the overall observed transport property of the thin films is like that of bulk crystals, there are several distinct features of the thin films. First, we observe superconducting transitions (resistivity drops) for the entire composition range, even at  $x = 0$  (FeTe) [Fig. 2(b)]. This observation contrasts with the report that superconductivity in the bulk single crystal is strongly suppressed below  $x \sim 0.05$  [17,18], where superconductivity competes with the AFM ordering and/or the AFM order-induced monoclinic structural distortion. Second, as shown in Fig. 2(c), the superconducting dome for our thin films peaks around  $x \sim 0.1$ , reaching an optimal  $T_c \sim 12$  K, which is quantitatively different from that of both bulk single crystals and other thin films grown on different substrates [24–26]. Third, the resistivity anomaly related to the structural phase transition at  $T_s$  cannot be clearly seen in our thin films, while bulk single crystals of the end compounds FeSe and FeTe are known to show

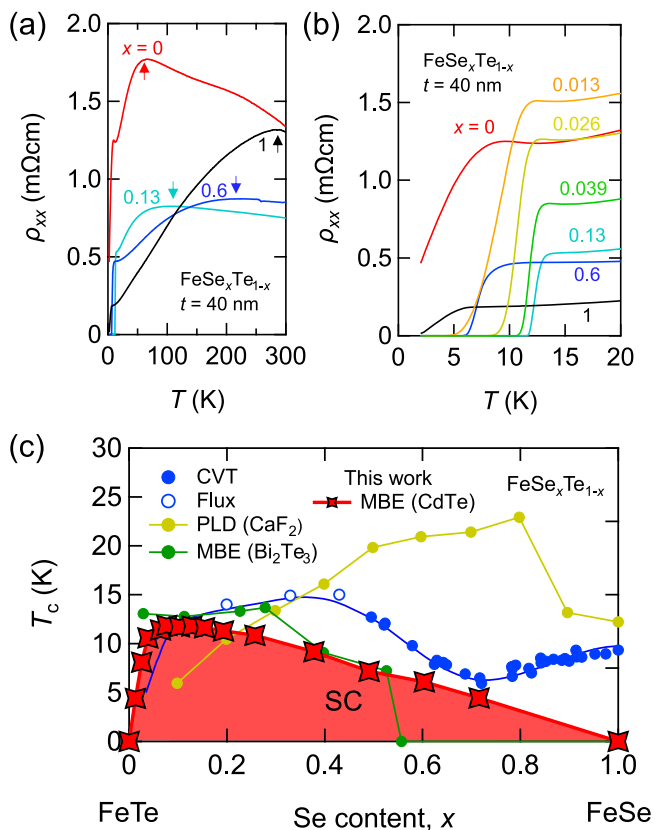


FIG. 2. Superconductivity in  $\text{FeSe}_x\text{Te}_{1-x}$  (FST) thin films grown on CdTe substrate. (a) Resistivity-temperature ( $\rho_{xx}$ - $T$ ) curves for FST thin films with different Se content  $x$ . The arrows indicate the temperature where  $\rho_{xx}$  takes its maximum. (b) The magnified  $\rho_{xx}$ - $T$  curves  $< 20$  K. (c) Phase diagram of FST as a function of  $x$ . The superconducting transition temperature  $T_c$  is defined by the zero resistance.  $T_c$  and superconducting region for FST thin films with  $t = 40$  nm are represented as red stars and red hatched area, respectively. The other markers represent  $T_c$  obtained by bulk single crystals grown by chemical vapor transport (CVT; blue filled circle [24]) and flux method (blue open circle [17]), thin films grown by pulsed laser deposition (PLD) on  $\text{CaF}_2$  (yellow circle [25]), and molecular beam epitaxy (MBE) on  $\text{Bi}_2\text{Te}_3$  (green circle [26]).

kink and jump anomalies at  $T_s \sim 90$  and  $70$  K, respectively. We will discuss this point in the following in more detail.

*Possible suppression of the first-order structural transition in thin film  $\text{FeSe}_x\text{Te}_{1-x}$ .* When materials are grown on substrates in the form of epitaxial thin films, their physical properties can be greatly affected by strain, charge transfer, and phonon coupling from the substrates [27,28]. This substrate effect appears to be of great importance especially for FST thin films, where multiple degrees of instability such as superconductivity, magnetism, and orbital ordering compete. This is likely the reason why the phase diagrams of FST are dramatically different depending on how the samples are grown, as shown in Fig. 2(c). Indeed, it has been pointed out that changes in lattice constants and bond angles can significantly influence  $T_c$  in both FeSe and FeTe thin films [29,30]. Furthermore, it is claimed that the substrate can substantially suppress the lattice structural transition in thin films of FeSe [31], which still holds anisotropy in the

electronic system, suggesting an electronically driven nematic state [32].

To check whether the observed transport properties are inherent features of FST thin films grown on CdTe substrate, we examine  $t$  dependence of transport properties to see how the thin film properties recover to those of bulk single crystals as  $t$  is increased. In Fig. 3(a), we present magnetic susceptibility  $\chi$  of three FeTe thin films with  $t = 40$ , 250, and 1000 nm as a function of  $T$ . The thickest sample ( $t = 1000$  nm) shows an abrupt drop below  $\sim 60$  K, which corresponds to the Néel temperature  $T_N$ . However, as  $t$  decreases, the sharpness of the AFM transition gets broader, and no significant drop in  $\chi$  was observed at  $T_N$  for the thinnest sample ( $t = 40$  nm). This broadening of the transition can be also seen in Hall coefficient  $R_H$ , as shown in Fig. 3(b). In the  $t = 1000$  nm sample,  $R_H$  shows sharp reduction below  $T_N$  and changes its sign from positive to negative. An even more sudden reduction of  $R_H$  and a sign change were also reported in the bulk single crystals [17], which is considered a consequence of Fermi surface reconstruction driven by bicollinear AFM ordering accompanied by the lattice structural transition to the monoclinic form. As  $t$  decreases, however,  $R_H$  becomes larger in magnitude, and the anomaly near  $T_N$  gets broader, showing no sign change down to 2 K in the  $t = 40$  nm film. A similar effect can be found in  $\rho_{xx}$ - $T$  curves of FeTe thin films, as shown in Fig. 3(c). While the thicker samples show a more pronounced drop of  $\rho_{xx}$  below  $T_N$ , the thinner sample shows a broader feature with relatively large resistivity. Because the sudden changes at  $T_N$  are likely due to the first-order phase transition nature of the structural instability, the broadening of  $\chi$  and  $R_H$  in the thinner samples implies that the structural instability is somewhat suppressed in the FeTe thin films. In addition to such suppressed structural transition, possible influence from the substrate can also be seen even at higher temperatures. To see the  $t$ -driven evolution of transport properties, we show  $t$  dependence of conductivity  $\sigma_{xx}$  and  $1/e R_H$ , reflecting carrier density in the case of a single-band model, at  $T = 150$  K well above  $T_N$  in Fig. 3(d). While both the quantities hold comparable values in thick samples with  $t \geq 200$  nm, they exhibit sudden drops below  $t \sim 100$  nm. These results imply that the electronic structure near the substrate might be different from that of the rest of the film and that such a region expands from the interface up to 100 nm or less, as schematically illustrated in the inset of Fig. 3(d). If such a region is superconducting, it is expected that superconductivity will be observed irrespective of  $t$ , even if the remaining parts are metallic. Indeed, we observed the onset of superconductivity in all three FeTe films we measured, as shown in Fig. 3(c) (see also the Supplemental Material [19]). It is interesting to know whether the FeTe thin films possess nearly perfect compensation of electron and hole or total carrier concentration is progressively reduced. However, it is difficult to estimate carrier concentration and mobility for both electron and hole separately because Hall resistivity shows nearly linear-in- $H$  dependence [19] up to 14 T. Further study is needed to clarify the fermiology in FeTe and its systematic evolution with  $x$  in these FST thin films.

We make a comparison between the phase diagrams for bulk single crystals and our MBE-grown FST films with  $t = 40$  nm shown in Figs. 3(e) and 3(f), respectively, focusing on the Te-rich region ( $0 \leq x \leq 0.2$ ). In the bulk crystals, the

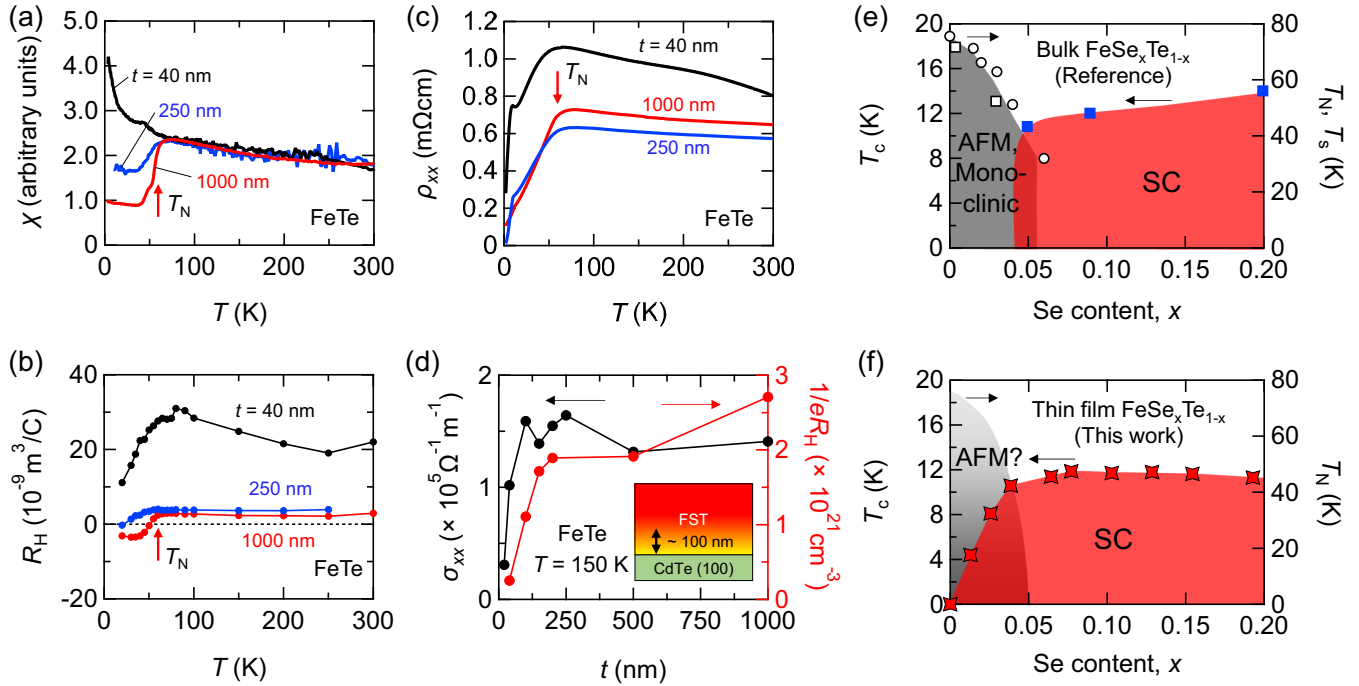


FIG. 3. Suppressed structural phase transition and robust superconductivity in Te rich  $\text{FeSe}_x\text{Te}_{1-x}$ . (a) Temperature  $T$  dependence of magnetic susceptibility  $\chi$  of FeTe films with different  $t$ , in which contribution from the substrate is subtracted. The red arrow indicates Néel temperature  $T_N$  for the  $t = 1000$  nm sample. (b)  $T$  dependence of Hall coefficient  $R_H$  of FeTe films with different  $t$ . (c)  $T$  dependence of resistivity  $\rho_{xx}$  of FeTe films with different  $t$ . (d)  $t$  dependence of conductivity  $\sigma_{xx}$  and  $1/eR_H$  for FeTe at 150 K. The yellow region describes the thickness region where electronic structure is significantly modified by the substrate effect. The inset depicts schematic of FST film. (e)  $T$ - $x$  phase diagram of bulk single crystals and (f) the present  $t = 40$  nm thin films in Te-rich region ( $0 \leq x \leq 0.2$ ). The blue square [17] in (e) and red star in (f) shows superconducting transition temperature  $T_c$ , while white circle [18] and square [17] represent  $T_N$ , which coincides with the structural phase transition temperature  $T_s$ .

AFM order accompanied by the monoclinic lattice distortion takes place below  $x \sim 0.05$ , and superconductivity is strongly suppressed in this region. In our MBE films, on the other hand, superconductivity survives even in the vicinity of  $x = 0$ , where superconductivity has never been observed in bulk. We note that  $T_c$  here is determined by the zero-resistivity temperature and that the drop in  $\rho_{xx}$  is observed even at  $x = 0$ . More detailed transport data in this Te-rich region are available in the Supplemental Material [19]. To understand the difference between the phase diagrams, it is important to clarify whether the AFM phase coexists with superconductivity. Recent spin-resolved STM studies revealed that the AFM order holds in few-layer FeTe films grown on different substrates [33,34]. The substrate effects appear to prevent the lattice structural transition in the FeTe, while they might keep AFM fluctuation or ordering intact. Consequently, the second-order AFM transition could lead to gradual changes, as observed in  $\rho_{xx}$  and  $R_H$  below  $T \sim 70$  K in the  $t = 40$  nm sample. The suppressed lattice structural transition suggests a potential difference in the Fermi surface topology between the thinner FeTe films and bulk single crystals, which could serve as a pivotal factor in stabilizing superconductivity in the Te-rich FST. However, one might interpret the gradual changes as observed in  $\rho_{xx}$  and  $R_H$  as an incoherent-coherent crossover [18] or, more specifically, Kondo-type band renormalization [35]. We need further investigation on the presence of long- or short-range magnetic order in our FST films and its influence on the observed superconductivity.

*Growth, characterization, and transport properties of  $(\text{Cr, Bi, Sb})_2\text{Te}_3/\text{FeSe}_x\text{Te}_{1-x}$  heterostructures.* We discuss the heterointerfaces between the magnetic TI CBST and the superconductor FST. It is reported that BT, the mother compound of CBST, can be grown on FeTe using the MBE technique, even though they have different lateral rotational symmetries of  $C_4$  (FeTe) and  $C_3$  (BT) [12,13] (dubbed hybrid epitaxy [26]). This unusual situation enables us to fabricate heterostructures even in the opposite stack order, i.e., FST/BT [36,37]. Interestingly, the heterostructure (BT/FT) between those nonsuperconducting materials can host interfacial superconductivity. Furthermore, nonreciprocal transport is observed in the BT/FT heterostructure, suggesting a strong coupling between the topological surface state and the superconducting proximity effect [13].

Figures 4(a) and 4(b) show the HAADF-STEM picture and EDX elemental mappings for a CBST/FST heterostructure. We observed a sharp interface between FST and CBST. Each element composing CBST and FST is homogeneously distributed and confined to the respective intended layers, demonstrating a high-quality heterointerface. In addition, we observed significant XRD intensities from both FST and CBST, as shown in Fig. 4(c). The observed peak positions agree well with those of thin films of CBST and FST, as indicated by blue and red down-triangles, respectively, suggesting a nearly distortion-free heterointerface. We also examined surface topographies taken by atomic force microscopy for as-grown FST and CBST/FST films [Fig. 4(d)]. The topography

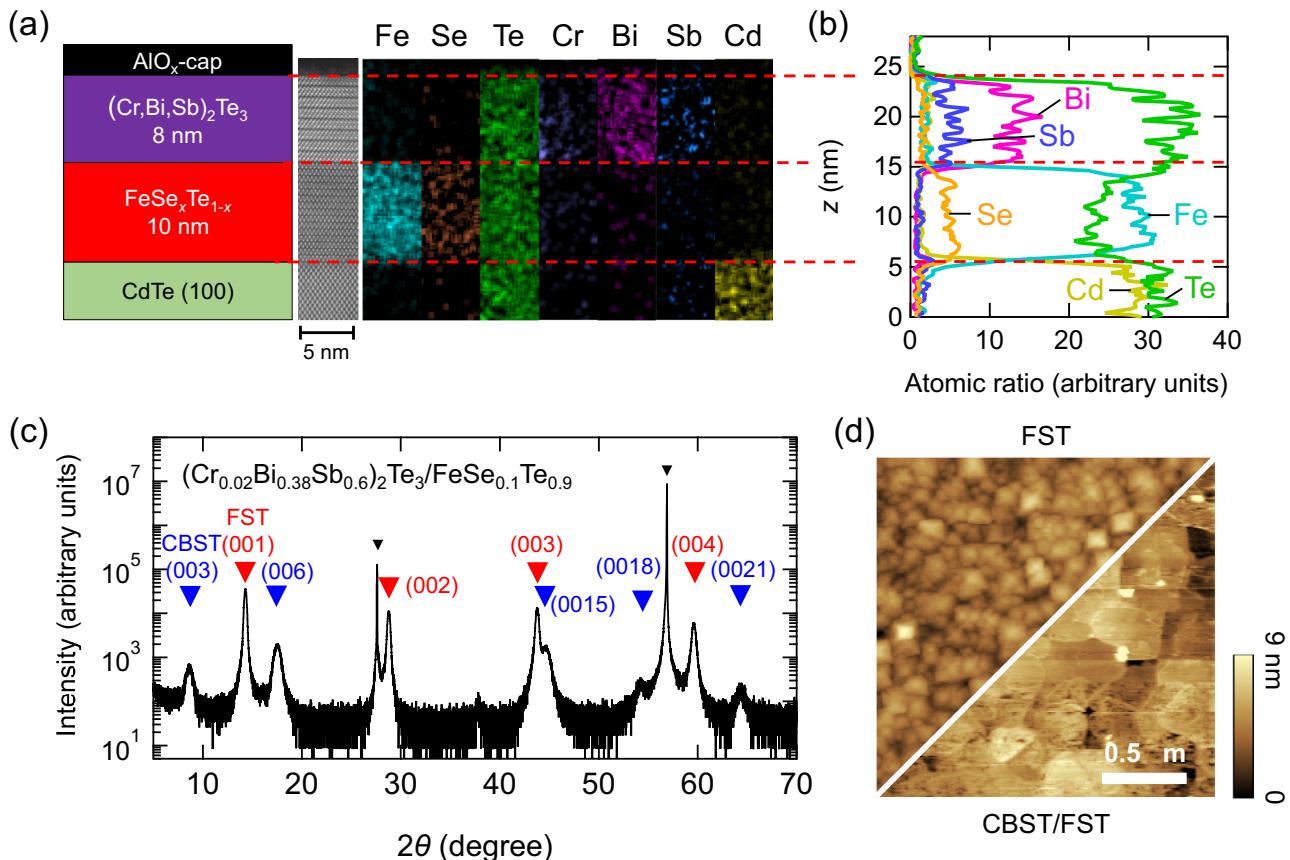


FIG. 4. Structural characterization of (Cr, Bi, Sb)<sub>2</sub>Te<sub>3</sub> (CBST)/FeSe<sub>x</sub>Te<sub>1-x</sub> (FST) heterostructure. (a) Real-space characterization of CBST/FST ( $x = 0.1$ ). (left) A schematic of the sample. (middle) Cross-sectional high-angle annular dark-field scanning transmission electron microscopy (HAADF-STEM) image. (right seven panels) Elemental mappings of comprising elements of Fe, Se, Te, Cr, Bi, Sb, and Cd obtained by an energy dispersive x-ray spectroscopy (EDX) for the same area shown in the HAADF-STEM image. The red dashed line depicts the boundary between the respective layers. (b) Laterally integrated atomic ratio profiles obtained by the EDX study in (a). (c) Semilog plot for x-ray diffraction (XRD) data of CBST/FST ( $x = 0.1$ ). The blue, red, and black down-pointing triangles denote the peaks from CBST(003 $n$ ), FST(00 $m$ ), and CdTe(100), respectively. (d) Atomic force microscopic image of FST (top left) and CBST/FST (bottom right). The white scale bar represents 0.5  $\mu\text{m}$ .

of FST is covered by small and squared patterns, whose edge is aligned to the CdTe(110) direction. After the deposition of CBST, the abovementioned structure disappears, and a larger terrace and steplike structure covering the whole scanned area shows up, which is reminiscent of that of MBE-grown CBST thin films [38].

We investigate transport properties of the CBST/FST heterostructure. Because the presence of Se in CBST is detrimental to the magnetic order necessary for the QAH effect, it is highly desirable to develop an all-Te heterostructure with minimal Se level. For this reason, it is essential to pursue Te-rich superconducting FST films in combination with FM CBST approaching quantization. In Fig. 5(a), we present longitudinal sheet resistivity  $R_{xx}$  of (Cr<sub>0.02</sub>Bi<sub>0.38</sub>Sb<sub>0.6</sub>)<sub>2</sub>Te<sub>3</sub>/FeSe<sub>0.1</sub>Te<sub>0.9</sub> with different  $t$  of FST as a function of  $T$ . The nominal composition used for the CBST layer is like the optimal conditions for observing the QAH effect in CBST single layers [5,39]. In a sample with  $t = 45$  nm, superconductivity is observed at  $T_c \sim 12$  K, which is as high as that of an FST single layer with  $x = 0.1$ . This indicates that, at  $t = 45$  nm, superconductivity in FST is hardly affected by CBST. As  $t$  decreases, however, we

observe a reduction in  $T_c$ , and the system finally becomes nonsuperconducting at  $t = 4$  nm. In the case of nonmagnetic heterostructure BT/FST, superconductivity is observed even at  $t = 4$  nm [19]. Considering this, the absence of superconductivity in the  $t = 4$  nm CBST/FST suggests that superconductivity is partly suppressed due to the magnetic proximity effect. In Fig. 5(b), we plot sheet conductance  $\sigma_{xx} = \rho_{xx}/(\rho_{xx}^2 + \rho_{yx}^2)$  of the CBST/FST films in the normal state ( $T = 20$  K) as a function of  $t$ . We observe an almost linear relationship between  $\sigma_{xx}$  and  $t$  with a nearly zero intercept, indicating that the longitudinal conductivity is mainly determined by FST. Therefore, CBST remains highly insulating, indicating that the Fermi energy in CBST is close to the charge neutral point, which is a prerequisite for the QAH effect. The negative intercept of  $\sigma_{xx}$  may indicate that the transport for the  $t = 4$  nm sample is severely affected by the magnetic proximity effect from CBST, which enhances magnetic scattering showing very insulating behavior. Importantly, we observe the anomalous Hall effect in the CBST/FST heterostructure, whose amplitude at zero field rapidly grows with lowering temperature [Fig. 5(c)]. The positive slope of  $\sigma_{xy} = \rho_{yx}/(\rho_{xx}^2 + \rho_{yx}^2)$  against the magnetic field  $H$  in the paramagnetic state

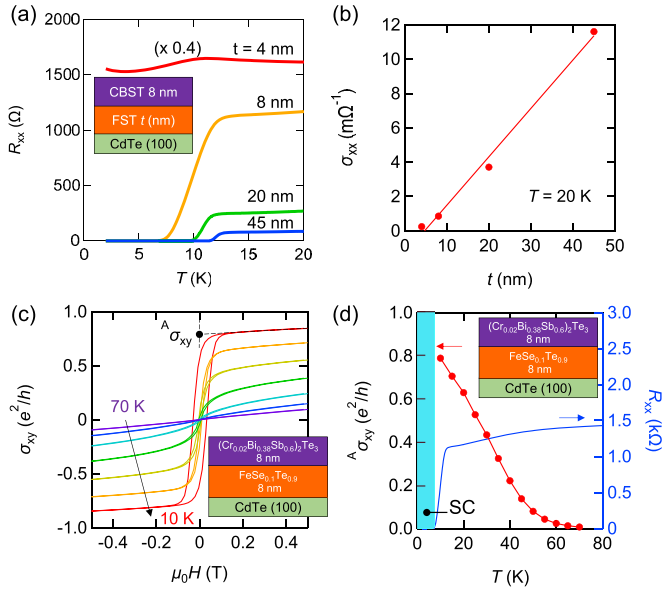


FIG. 5. Superconductivity and large anomalous Hall effect in a magnetic topological insulator/superconductor heterostructure. (a) Temperature  $T$  dependence of longitudinal sheet resistance  $R_{xx}$  of  $(\text{Cr}_{0.02}\text{Bi}_{0.38}\text{Sb}_{0.6})_2\text{Te}_3$  (CBST)/ $\text{FeSe}_x\text{Te}_{1-x}$  (FST) ( $x = 0.1$ ) heterostructure with different thickness  $t$  of FST. The inset is schematics of our device. (b) Sheet conductivity  $\sigma_{xx}$  vs  $t$  at 20 K. The line is a linear fit for the data. (c) Field  $H$  dependence of sheet Hall conductivity  $\sigma_{xy}$  of CBST/FST ( $x = 0.1$  and  $t = 8$  nm). The data are taken from 10 to 70 K with 10 K intervals. Anomalous Hall conductivity  $A\sigma_{xy}$  is determined by the extrapolation for each datum from high field. (d)  $A\sigma_{xy}$  (left axis) and  $R_{xx}$  (right axis) as a function of  $T$ . The shaded area is superconducting phase, where  $R_{xx}$  drops to zero and Hall conductivity is not measurable.

$\sim 70$  K, where the anomalous Hall signal disappears, is comparable with that of FST [19], indicating that the ordinary Hall effect of CBST is negligibly small. We then plot the anomalous Hall conductivity  $A\sigma_{xy}$ , obtained by extrapolation from high field, against  $T$  [Fig. 5(d)]. Here,  $A\sigma_{xy}$  starts to increase at  $T_{\text{Curie}} \sim 65$  K and reaches as high as  $0.8e^2/h$  at 10 K, above the superconducting transition. Although observing the QAH effect in CBST requires very low temperature, typically well below 1 K [5], we cannot measure the Hall conductance of CBST/FST at lower temperatures because the superconducting FST completely shunts Hall voltage below  $T_c$ . However, the reasonably large  $A\sigma_{xy} \sim 0.8e^2/h$  at 10 K and  $T_{\text{Curie}}$  of  $\sim 65$  K are comparable with those for CBST thin films, which show the well-defined QAH effect at temperatures  $< 1$  K [39]. Therefore, it is natural to consider that the CBST/FST heterostructure has a well-developed exchange gap on the CBST side and a superconducting gap on the FST side at temperatures below  $T_c$ .

The observed large anomalous Hall conductivity approaching the QAH state and superconductivity in the CBST/FST heterostructure fulfills the prerequisites for the emergence of chiral Majorana edge modes. We note that this exotic quantum Hall insulator/topological superconductor heterostructure may be utilized to detect much concrete evidence of multiple chiral Majorana edge modes [40]. Recently, it was predicted that chiral Majorana edge modes are also detectable through local optical conductivity [41]. This paper therefore may trigger further experimental attempts to investigate Majorana excitations in topological superconductors.

**Conclusions.** To summarize, we demonstrate the successful fabrication of homogeneous FST thin films by using the MBE method throughout the entire composition of  $0 \leq x \leq 1$ . The FST films show a single superconducting dome which peaks at  $\sim 12$  K around the optimal composition of  $x = 0.1$  in the  $T_c - x$  phase diagram. Remarkably, superconductivity can survive in the very Te-rich composition of  $x \leq 0.05$ , whereas it is completely suppressed in bulk single crystals. We attribute this difference in phase diagrams to possible substrate effects that substantially suppress the first-order structural transition and greatly modify the electronic structure. The extremely Te-rich superconducting FST may not suffer from the inhomogeneity problem, making it an ideal candidate for studying Majorana zero modes by STM. Additionally, we demonstrate the fabrication of a heterointerface between magnetic TI CBST and superconductor FST, both based on tellurides with large spin-orbit coupling and possibly small carrier densities. This heterostructure exhibits a large anomalous Hall conductivity in the normal state and superconductivity below  $T_c$ . Our results, therefore, present an important step toward establishing a concrete materials platform to explore Majorana excitations in solids.

*Note added.* During the peer review process, we became aware of a related study on CBST/FeTe heterostructures [42]. Our CBST/FST heterostructure has the same composition except for the inclusion of Se into FeTe. The advantage of Se doping is that it can provide a more robust bulk-origin superconducting proximity effect to the magnetic TI, while maintaining a large magnetic gap. Indeed, the CBST/FST heterostructure allows us to incorporate high Cr concentration in CBST, thereby maintaining both robust superconductivity and a large anomalous Hall conductivity approaching  $e^2/h$ .

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